

Proceedings



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- Presented at CSAC2021: The 1st International Electronic Conference on Chemical Sensors and Analytical Chemistry, online, 01-15 July 2021.

### Abstract:

In the present work, it has been shown that bismuth film electrodes deposited on screen-printed13carbon supports could be successfully used to provide well-shaped, sensitive and reproducible cat-14alytic adsorptive stripping signals of Ge (IV) in the presence of catechol and V(IV)-HEDTA (HEDTA15- N-hydroxyethyl-ethylene diamine-triacetic acid) complex.16

Keywords: film electrodes; germanium; stripping voltammetry

# 1. Introduction

Germanium represents a unique group of elements known as Critical Raw Materials 20 (EU). Although such elements typically constitute only a small percentage of a material 21 by weight, they are essential to its performance [1]. Among the numerous analytical tech-22 niques available, voltammetry seems to have much to offer in this regard as voltammetric 23 techniques are insensitive to the presence of inorganic salts and, at the same time, they 24 offer low detection limits. Among voltammetric methods, catalytic adsorptive stripping 25 voltammetry (CAdSV) plays an essential role in trace analysis due to its remarkable sen-26 sitivity. To induce a catalytic effect which gives the method its outstanding sensitivity, 27 ions with oxidizing properties must be added to the examined solution, e.g., nitrate, ni-28 trite, bromate, or chlorate. Unfortunately, many electrode materials, both metallic sensing 29 layers as well as auxiliary polymers, are damaged under the influence of these oxidants. 30

As it was reported earlier, using HMDE or silver-amalgam working electrodes and 31 the supporting electrolyte containing V(IV)-HEDTA (HEDTA - N-hydroxyethyl-ethylene 32 diamine-triacetic acid) complex (Figure 1), catechol or its derivatives, the well-developed 33 germanium signals could be recorded at nM level [2,3]. To develop a workable analytical 34 procedure for the detection of trace amounts of germanium, and to meet the current 35 guidelines that impose limitations on the application of mercury in chemical and analyti-36 cal laboratories, an environmentally friendly alternative should be employed instead. The 37 metallic film electrodes, such as bismuth (BiFE) and lead (PbFE) electrodes are among the 38 most widely used sensors in the field of stripping voltammetry [4]. 39

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Published: 1 July 2021

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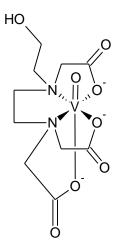


Figure 1. The structure of V(IV)-HEDTA complex.

This work aims to assess the applicability of lead and bismuth film electrodes depos-2ited electrochemically or by physical deposition from gaseous phase on different supports3to provide catalytic adsorptive stripping signals of Ge(IV) in the presence of catechol and4V(IV)-HEDTA complex.5

# 2. Materials and Methods

Electrochemical study was performed on a Autolab 204 analyser (Metrohm Autolab, 7 Switzerland). Disposable screen-printed electrodes (4 mm diameter) (DropSens, Spain) or 8 disc electrodes (3 mm diameter) made of glassy carbon or gold (Mineral, Poland) were 9 used as supports for bismuth films. Platinum wire and Ag/AgCl(3M KCl) were applied as 10 the anode and reference electrodes. All applied reagents were analytical grade. 11

Lead and bismuth films were plated just prior to use by means of potentiostatic dep-12 osition. Before plating, the disc substrates were polished using an Al<sub>2</sub>O<sub>3</sub> suspension (0.3 13 and 0.05 µm) applied onto a polishing cloth. Screen-printed electrodes did not require any 14 preparation or processing other than 2 minutes of soaking in the plating solution imme-15 diately prior to electrolysis. The plating process performed in quiescent 0.34 M HClO<sub>4</sub> 16 containing 0.043 M of Bi(III) or stirred 0.2 M acetate buffer containing 0.003M Pb(II) was 17 monitored by recording chronoamperometric curves and stopped when the charge 18 reached the defined threshold (E<sub>plat</sub> = -0.9 V, Q<sub>plat</sub> = 0.8 mC per mm<sup>2</sup>). Pre-plated electrodes 19 were rinsed with 0.1 M acetate buffer (PbFE) or 0.34 M HClO<sub>4</sub> (BiFE) and water. The PVD 20 deposition followed the protocol described in the previous work [5]. 21

The supporting electrolyte contained 0.05 M acetate buffer (pH of 4.4), 1 mM of catechol, 1 mM of V(IV) and 1.5 mM of HEDTA. CAdSV voltammograms were recorded after 30 s of accumulation performed at the potential of -0.6 V (PbFE) or -0.4 V (BiFE) by differential pulse mode. 22

### 3. Results and discussion

#### 3.1. Support selection

To deposit the metallic sensing layers, the following supports were considered: (1) 28 carbon-based electrodes: glassy carbon, carbon paste, impregnated carbon, screen printed 29 carbon and (2) gold-based electrodes: bulk disc, PDV deposited gold, gold screen printed. 30 The sensing layers were deposited electrochemically by ex situ plating or by PVD deposi-31 tion. The preliminary tests of freshly prepared films rinsed with water were performed by 32 microscopic inspection. In the case of carbon-based supports and bismuth films, the visual 33 changes were not pronounced, as the plating only gave the surface a black, velvety ap-34 pearance. In the case of lead deposits, the electrode surface was turned gray. In the case 35

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of gold supports, the results were more complex. While the expected finding was that the 1 type of the support (gold monolithic disc, gold screen printed layer, or PVD deposited 2 gold) does not play the key role, this study showed that the method of support prepara-3 tion plays an important role. The films deposited on the gold disc electrode were very 4 stable and adhesive. The lead layers deposited on the SPE or PVD gold were oxidized 5 within minutes once removed from the plating solution (Figure 2). In the case of bismuth, 6 the oxidation at AuSPE was slower but unrelenting. Information on the mechanism of 7 oxidation of the metallic layer was provided by analysis of the bismuth films deposited 8 on the microscratched Au PVD layer (Figure 3 a-c). The microscopic images revealed the 9 bismuth crystallites formed near microscratches are susceptible to oxidation. Gradually 10 the gold support was exposed, but after 10 minutes further changes were not observed as 11 the bismuth crystallites adjacent to the scratches were depleted. The color histograms of 12 microscopic images of Bi deposited on AuPVD shown in Figure 3d have not demonstrated 13 any further changes for pictures taken 10 and 12.5 minutes after removal from the plating 14 solution. The microanalysis performed by SEM XRF, and XRD studies of AuSPE as well 15 as AuPVD electrodes did not reveal other elements than gold. Some insight was provided 16 by contact angle measurements, displaying a significant difference in wettability of PVD 17 gold (68.0±0.2°) and SPE (92.0±0.3°) electrodes. Since the surface microstructure of mate-18 rials correlates closely with the apparent contact angle at the boundary between the liquid 19 and the surface, the different surface properties of AuSPE and AuPVD were confirmed. 20 The AuPVD contact angle value corresponds well to earlier reported values [6], while 21 those obtained for AuSPE are substantially higher, placed on the threshold of hydropho-22 bicity. The high contact angle can be explained by the rough three-dimensional structure 23 of the gold layer, preventing the access of water molecules to the electrode surface by 24 trapped air or by organic compounds of the ink used for screen printing. Regardless of 25 cause, the gold screen printed electrodes cannot be used for bismuth or lead ex situ plat-26 ing. 27

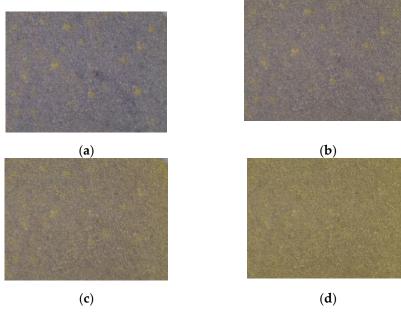
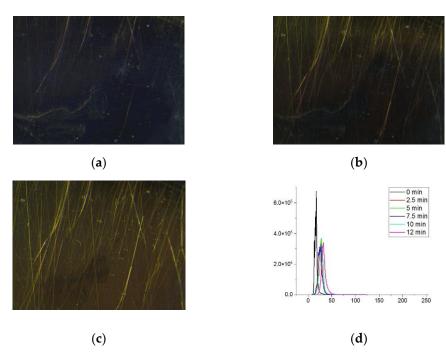


Figure 2. Microscopic images of Pb plated gold SPE recorded after 0 (a), 2.5 (b), 5 (c), and 7.5 (d) minutes after plating. Gray regions represent the lead layer while yellow the exposed gold support. . 30



**Figure 3.** Microscopic images of Bi plated gold sputtered electrode recorded 0 (**a**), 2.5 (**b**), and 12 (**c**) minutes after plating (150x; images brightened to make the details more visible). Color histogram analysis of the bismuth layer plated on the sputtered gold electrode (**d**) (https://www.dcode.fr/image-histogram).

# 3.2. Stability studies of metallic films in contact with V(IV)-HEDTA solution

The externally plated bismuth and lead films as well as PVD deposited bismuth and 6 lead layers were exposed to the supporting electrolyte containing the V(IV)-HEDTA com-7 plex, catechol and acetate buffer. Employing bismuth film electrodes of any type, it was 8 possible to record well-shaped germanium signals in solutions containing from a few to 9 several hundred nM of germanium. In the case of lead film electrodes only PbFE depos-10 ited on glassy carbon, carbon paste and impregnated carbon provided measurable germa-11 nium signals. Lead layers deposited on SPE supports of any type did not deliver any ger-12 manium signals. Although the signals recorded by the most promising lead electrode, 13 namely, PbFE/GC, in the solution containing 30 nM of Ge(IV), were initially quite pro-14nounced, there was no Ge(IV) signal after recording ten or so voltammograms. In this 15 way, the unsuitability of PbFEs for their intended use in stripping voltammetry became 16 apparent. 17

### 3.2. Analytical performance of bismuth plated screen printed electrodes

It was shown [2] that when the HMDE electrode was used as the working electrode, 19 the catalytic activity of HEDTA vanadium complexes towards the germanium complex 20 was correlated with the redox behavior of V(IV)-HEDTA. In the case of pyrogallol germa-21 nium complexes, the intensity of the germanium signal correlated with the characteristics 22 of the voltammetric signal representing the reduction of the V(IV) complex [3]. The cyclic 23 voltammograms shown in Figure 4 a were recorded by means of bismuth plated glassy 24 carbon and carbon SPE electrodes and compared with the curves obtained when CGMDE 25 and GC were used. Both CGMDE and GC delivered well-shaped reversible voltammo-26 grams of V(IV)-HEDTA complex, while at BiFE electrodes only reduction signals were 27 observed. Such behavior indicates that the catalytic process at BiFEs proceeds following a 28 different mechanism than that observed at CGMDE. 29

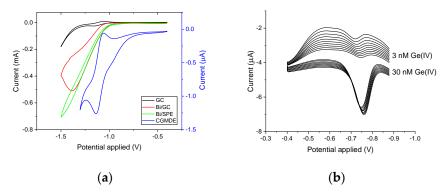
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**Figure 4.** CV voltammograms recorded in an 0.05 M acetate buffer containing 1 mM of V(IV) and 2 mM of HEDTA using glassy carbon (GC), bismuth plated glassy carbon (BiFE/GC), bismuth plated screen printed carbon electrode (BiFE/SPE) and a controlled-growth mercury drop electrode (CGMDE). Scan rate =  $50 \text{ mVs}^{-1}$  (a). Ten consecutive differential pulse voltammograms recorded by Bi/SPE electrode in the solution containing 3 or 30 nM of Ge(IV) and 0.05 M acetate buffer (pH of 4.4), 1 mM of catechol, 1 mM of V(IV) and 1.5 mM of HEDTA (b).

The catalytic signals of Ge(IV) recorded at BiFE/SPE in the presence of V(IV)-HEDTA 7 were pronounced and highly reproducible, as it is shown in Figure 4 b. The calibration 8 curve is given by the equation  $y = (0.083\pm0.001)x+(0.06\pm0.01)$  (r<sup>2</sup> = 0.9989), where y and x 9 denote the peak current (µA) and Ge(IV) concentration (nM). The I<sub>p</sub> = f(cGe(IV)) is linear 10 within the range from 2 to 30 nM (LOD = 1.5 nM). Finally, BiFE/SPEs were applied for 11 Ge(IV) determination in Ge(IV) spiked snow water (10 nM) via the standard addition 12 method and the concentration of 10.05±0.11 nM was determined. 13

## 3. Conclusion

The results reported here demonstrate that the properties of lead and bismuth film electrodes differ considerably and only bismuth plated electrodes enable germanium analytical signals to be obtained when Ge(IV)-catechol-V(IV)-HEDTA system is employed.

Author Contributions: Conceptualization, A.K.; methodology, A.K.; software, A.K.; writing—orig-19inal draft preparation, A.K.; writing—review, A.B. and J.Z.; visualization, A.K.;. All authors have20read and agreed to the published version of the manuscript.21

**Funding:** This work was supported by the subsidy of the Ministry of Education and Science for the AGH University of Science and Technology in Kraków (Project No 16.16.160.557).

Conflicts of Interest: The authors declare no conflict of interest.

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